

# Monolithic Amplifier

# **PHA-202+**

Mini-Circuits

50Ω 0.03 to 2.7 GHz

### **THE BIG DEAL**

- Ultra High IP3, +46.1 dBm
- Broadband High Dynamic Range without external Matching Components
- Medium power, 1W
- Excellent return loss over 15 dB
- High IP3, +46.1 dBm typ. at 1 GHz
- Gain, 17.0 dB typ. at 1 GHz
- High P<sub>OUT</sub>, P1dB +30.4 dBm typ. at 1 GHz
- No external matching components required



Generic photo used for illustration purposes only CASE STYLE: DL1636

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our website for methodologies and qualifications

### **APPLICATIONS**

- Base station infrastructure
- CATV
- LTE

### **PRODUCT OVERVIEW**

The PHA-202+ (RoHS compliant) is a medium power amplifier fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the PHA-202+ has good input and output return loss over a broad frequency range without the need for external matching components and has demonstrated excellent reliability. It has repeatable performance from lot to lot and is enclosed in a 5mm x 6mm, 8 lead package for very good thermal performance.

#### **KEY FEATURES**

Feature	Advantages	
Broad Band: 0.03 to 2.7 GHz	Broadband covering primary wireless communications bands: Cellular, PCS, LTE	
Extremely High IP3 Versus DC power Consumption +46 dBm typical at 1.0 GHz	<ul> <li>The PHA-202+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being typically 14-23 dB above the P1dB point. This feature makes this amplifier ideal for use in:</li> <li>Driver amplifiers for complex waveform up converter paths</li> <li>Drivers in linearized transmit systems</li> <li>Secondary amplifiers in ultra High Dynamic range receivers</li> </ul>	
No External Matching Components Required	Unlike competing products, Mini-Circuits PHA-202+ provides Input and Output Return Loss of over 15 dB up to 2 GHz without the need for any external matching components	

REV. A ECO-010399 PHA-202+ MCL NY 240722

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# **ULTRA HIGH DYNAMIC RANGE** Monolithic Amplifier

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## ELECTRICAL SPECIFICATIONS<sup>1</sup> AT +25°C, 50 OHMS, UNLESS NOTED OTHERWISE

Deversiter	Condition	Vd=+11V <sup>1</sup>			Vd=+11V <sup>2</sup>	
Parameter	(MHz)	Min.	Тур.	Max.	Тур.	Units
Frequency range		0.03		2.7	0.03-2.7	GHz
	30	_	18.3	_	18.3	
	500	_	17.9	_	17.7	
Gain	1000	_	17.0	_	16.8	dB
	2000	13.2	14.7	16.1	14.3	
	2700	_	12.7	_	12.1	
	30		21.2		20.5	
	500		21.7		25.5	
nput Return Loss	1000		19.5		28.6	dB
	2000		20.3		17.7	
	2700		14.9		12.0	
	30		15.1		15.5	
	500		16.4		15.2	
Output Return Loss	1000		19.4		15.7	dB
	2000		22.5		19.1	
	2700		9.8		9.4	
Reverse Isolation	2000		23		23.3	dB
	30		+28.4		+29.2	
	500		+30.2		+29.8	
Output Power @1dB Compression	1000		+30.4		+29.8	dBm
	2000		+28.1		+27.0	
	2700		+25.7		+25.2	
	30		+51.0		+50.3	
	500		+48.5		+48.8	
Output IP3 <sup>3</sup>	1000		+46.1		+46.2	dBm
	2000		+43.2		+41.7	
	2700		+39.4		+38.8	
	30		3.2		3.0	
	500		3.3		3.0	
Noise Figure	1000		3.5		3.3	dB
	2000		4.4		4.3	
	2700		5.4		5.2	
Device Operating Voltage			+11		+11	V
Device Operating Current		_	350	416	335	mA
Device Current Variation vs. Temperature <sup>4</sup>			188.6		188.6	µA/°C
Device Current Variation vs Voltage <sup>5</sup>			0.0485		0.0485	mA/mV
Thermal Resistance, junction-to-ground lead at 85°C stage temp.			16.1		16.1	°C/W

1. Measured on Mini-Circuits Characterization test board MB018. See Characterization Test Circuit (Fig. 1) 2. Measured on Mini-Circuits Application test board TB-962+. See Characterization Test Circuit (Fig. 2)

3. Tested at Pout=16dBm / tone. 4. (Current at 85°C – Current at -45°C)/130 5. (Current at 11.5V-current - Current at 10.5V)/1000

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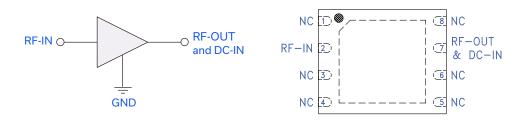
50Ω 0.03 to 2.7 GHz

### **ABSOLUTE MAXIMUM RATINGS<sup>6</sup>**

Parameter	Ratings		
Operating Temperature (ground lead)	-40°C to +85°C		
Storage Temperature	-65°C to +150°C		
Junction Temperature	179°C		
Power Dissipation	5.8 W		
Input Power (CW)	+24 dBm (5 minutes max.) +19 dBm (continuous)		
DC Voltage on Pin 7	+14 V		

6. Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.

## SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION



Function	Pin Number	Description
RF-IN	2	RF input
RF-OUT and DC-IN	7	RF output and DC input
GND	Paddle	Ground
NC	1,3-6,8	No connection



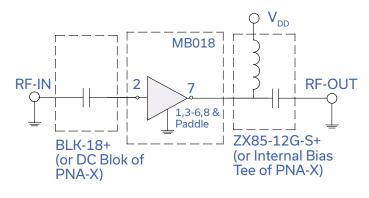
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## **CHARACTERIZATION TEST CIRCUIT**



#### Fig 1. Characterization Circuit

Note: This block diagram is used for characterization. (DUT soldered on Mini-Circuits Characterization test board MB018)

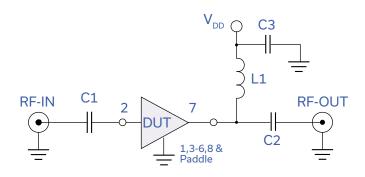
Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

1. Gain and Return loss: P<sub>IN</sub>= -25dBm

2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 16 dBm/tone at output.

### **RECOMMENDED APPLICATION CIRCUIT**



Component	P/N	SUPPLIER	Value	Size
C1, C2, C3	GRM- 155R71E103KA01D	MURATA	0.01uF	0402
L1	WA8514-AE	COILCRAFT	5.6uH	1708

Fig 2. Application Circuit

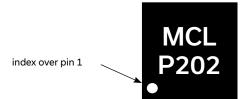
Note: (DUT soldered on Mini-Circuits Application test board TB-962+) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

#### Conditions:

1. Gain and Return loss: P<sub>IN</sub>= -25dBm

2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 16 dBm/tone at output.

### **PRODUCT MARKING**



Marking may contain other features or characters for internal lot control

#### Mini-Circuits www.minicircuits.com P.O. Box 350166, Brooklyn, NY 11235-0003 (718) 934-4500 sales@minicircuits.com PAGE 4 OF 5



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## ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. CLICK HERE

	Data Table
Performance Data	Swept Graphs
	S-Parameter (S2P Files) Data Set (.zip file)
Case Style	DL1636 Plastic package, exposed paddle lead finish: Matte Tin
Tape & Reel Standard quantities available on reel	F68 7″ reels with 20, 50, 100, 200, 500 or 1K devices 13″ reels with 2K, 3K, 4K devices
Suggested Layout for PCB Design	PL-522
Evaluation Board	TB-962+
Environmental Ratings	ENV08T1

### **ESD RATING**

Human Body Model (HBM): Class 1B (Pass 500V) in accordance with ANSI/ESD STM 5.1 - 2001

### **MSL RATING**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

NOTES

A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.

B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.

C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

